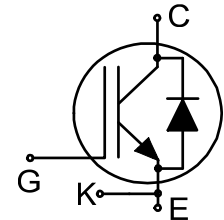


Sixth generation, high speed soft switching series

High speed soft switching TRENCHSTOP™ IGBT 6 in Trench and Fieldstop technology copacked with soft and fast recovery anti-parallel diode

**Features:**

- 1200V TRENCHSTOP™ IGBT6 technology offering:
- High efficiency in hard switching and resonant topologies
  - Easy paralleling capability due to positive temperature coefficient in  $V_{CEsat}$
  - Low EMI
  - Low Gate Charge  $Q_g$
  - Very soft, fast recovery full current anti-parallel diode
  - Maximum junction temperature 175°C
  - Pb-free lead plating; RoHS compliant
  - Complete product spectrum and PSpice Models:  
<http://www.infineon.com/igbt/>



**Applications:**

- Industrial UPS
- Charger
- Energy storage
- Three-level Solar String Inverter
- Welding

**Product Validation:**

Qualified for industrial applications according to the relevant tests of JEDEC47/20/22



**Key Performance and Package Parameters**

Type	$V_{CE}$	$I_C$	$V_{CEsat}, T_{vj}=25^{\circ}C$	$T_{vjmax}$	Marking	Package
IKY75N120CS6	1200V	75A	1.85V	175°C	K75MCS6	PG-TO247-4-2

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